

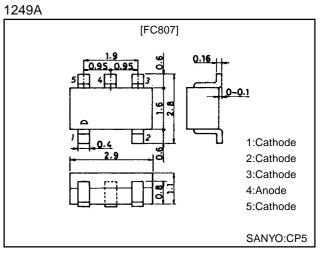
Silicon Epitaxial Planar Type High-Speed Switching Composite Diode (Anode Common)

Features

- Composite type with 4diodes contined in the CP package currently in use, improving the mouting efficiency greatly.
- \cdot Fast switching speed.

Package Dimensions

unit:mm



FC807

Specifications

Absolute Maximum Ratings at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|-------------------|------------|-------------|------|
| Peak Reverse Voltage | V _{RM} | | 85 | V |
| Reverse Voltage | V _R | | 80 | V |
| Surge Current | IFSM | 10ms* | 2 | A |
| Average Rectified Current | IO* | | 100 | mA |
| Peak Forward Current | I _{FM} * | | 300 | mA |
| Allowable Power Dissipation | P* | | 200 | mW |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Note*: Unit rating. The total rating is 150% of the unit rating.

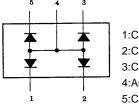
Electrical Characteristics at Ta = 25°C

| Parameter | Symbol | Conditons | Ratings | | | Unit |
|---------------------------|----------------|--|---------|------|-----|------|
| Falanielei | | | min | typ | max | |
| Forward Voltage | ٧ _F | I _F =10mA | | 0.72 | 1.0 | V |
| | | I _F =100mA | | 0.88 | 1.2 | V |
| Reverse Current | I _R | V _R =50V | | | 0.1 | μA |
| | | V _R =80V | | | 0.5 | μA |
| Interterminal Capacitance | С | V _R =0V, f=1MHz | | 4.5 | 9.0 | pF |
| Reverse Recovery Time | trr | I _F =10mA, V _R =6V, R _L =50Ω, i _{rr} =0.1Irp | | | 8.0 | ns |

Note: The specifications shown above are for individual diode.

Marking:807

Electrical Connection





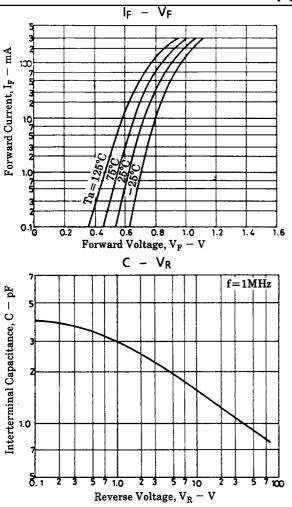


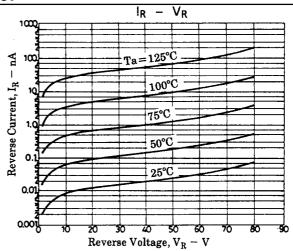


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